

6MBI300V-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 300A / 6 in one package

■ Features

Compact Package P.C.Board Mount Low VcE (sat) RoHS Compliant product

■ Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items			Symbols	Conditions		Maximum ratings	Units	
	Collector-Emitter voltage		V _{CES}			1200	V	
	Gate-Emitter voltage		V _{GES}			±20	V	
_	Collector current		Ic	Continuous	Tc=25°C	450		
rter			Icp		Tc=100°C	300		
nve			I _{C pulse}	1ms		600	Α	
-			-Ic			300		
			-I _{C pulse}	1ms		600		
	Collector power dissipation		Pc	1 device		1600	W	
Jui	nction tempera	ture	Ti			175		
Operation temperature (under switching conditions)			T _{jop}			150	°C	
Case temperature			Tc			125	C	
Storage temperature			T _{stg}			-40 to +125		
	between terminal and copper base (*1)	V	AC : 1min.		2500	\/A.C		
ISC	between thermistor and others (*2				V _{iso}	2500	VAC	
6-	crew torque	Mounting (*3)	-			3.5	N m	
SCI		Terminals (*4)	-			4.5	IN III	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

Note *4: Recommendable value : 3.5-4.5 Nm (M6)

1

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● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Cumbala	Conditions		Characteristics			Units
ite	ems	Symbols	Conditions		min.	typ.	max.	Units
	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	3.0	mA
	Gate-Emitter leakage current	Iges	$V_{GE} = 0V, V_{GE} = \pm 20V$		-	-	600	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 300mA		6.0	6.5	7.0	V
	Collector-Emitter saturation voltage		V _{GE} = 15V I _C = 300A	T _j =25°C	-	2.20	2.65	V
		V _{CE (sat)} (terminal)		T _j =125°C	-	2.50	-	
		(terrinial)		T _j =150°C	-	2.55	-	
			V _{GE} = 15V I _C = 300A	T _j =25°C	-	1.75	2.20	
		V _{CE (sat)} (chip)		T _j =125°C	-	2.05	-	
		(Criip)		T _j =150°C	-	2.10	-	
	Internal gate resistance	R _{G(int)}	-		-	2.50	-	Ω
ē	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	27	-	nF
Inverter	Turn-on time	ton	\/ 000\/	-	550	-	nsec	
		t	V _{cc} = 600V I _c = 300A	-	180	-		
		t _{r (i)}	V _{GE} = ±15V	-	120	-		
		toff	R _s = 0.93Ω L _s =80nH		-	1050		-
	Turn-off time	t _f			-	110		-
	Forward on voltage		V _{GE} = 0V I _F = 300A	T _j =25°C	-	2.15	2.60	- V
		V _F		T _j =125°C	-	2.30	-	
		(terminal)		T _j =150°C	-	2.25	-	
			V _{GE} = 0V I _F = 300A	T _j =25°C	-	1.70	2.15	
		V _F		T _j =125°C	-	1.85	-	
		(chip)		T _j =150°C	-	1.80	-	
	Reverse recovery time	trr	I _F = 300A		_	200	-	nsec
ō		_	T = 25°C		-	5000	-	Ω
Thermistor	Resistance	R	T = 100°C		465	495	520	
The	B value	В	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

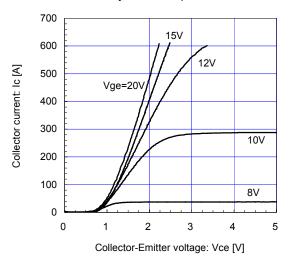
me	Symbols	Conditions	Characteristics			Units
Items	Syllibols		min.	typ.	max.	Ullits
Thermal resistance (1device)	R _{th(j-c)}	Inverter IGBT	-	-	0.094	°C/W
Thermal resistance (Tuevice)		Inverter FWD	-	-	0.150	
Contact thermal resistance (1device) (*5)	R _{th(c-f)}	with Thermal Compound	-	0.0167	-	

Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

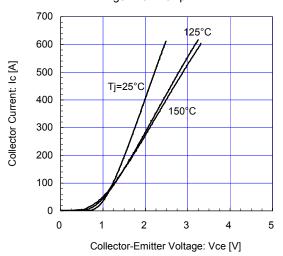
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



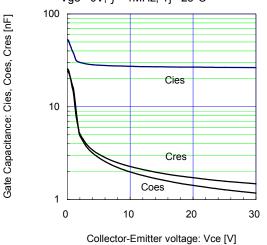
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Vge= 15V / chip



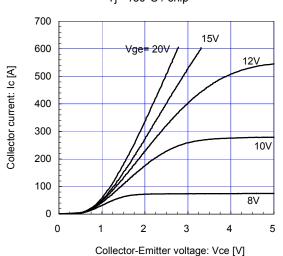
[INVERTER]

Gate Capacitance vs. Collector-Emitter Voltage (typ.) Vge= 0V, f= 1MHz, Tj= 25°C



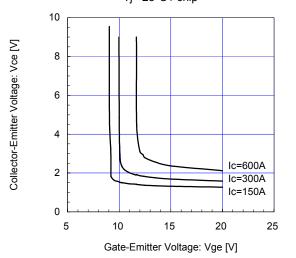
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



[INVERTER]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip



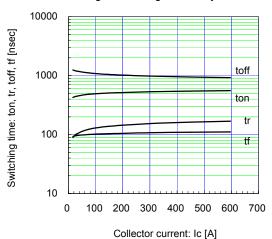
[INVERTER]

Dynamic Gate Charge (typ.) Vcc=600V, Ic=300A, Tj= 25°C 20 1000 800 15 Collector-Emitter voltage: Vce [V] Vce Gate-Emitter voltage: VGE [V] 600 10 400 5 200 0 0 -200 -5 -400 VGE -10 -600 -15 -800 -20 -1000 -3000 -1500 0 1500 3000

Gate charge: Qg [nC]

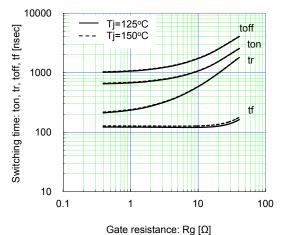
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, Vge= \pm 15V, Rg=0.93 Ω , Tj=25°C



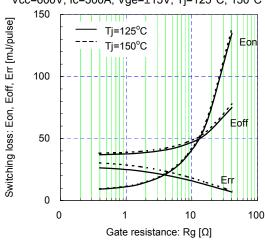
[INVERTER]

Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=300A, Vge=±15V, Tj=125°C, 150°C



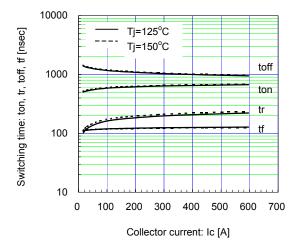
[INVERTER]

Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=300A, Vge=±15V, Tj=125°C, 150°C



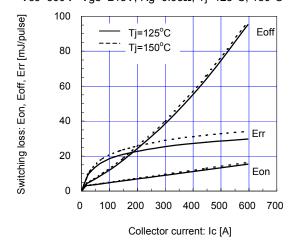
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, Vge= \pm 15V, Rg=0.93 Ω , Tj=125°C, 150°C



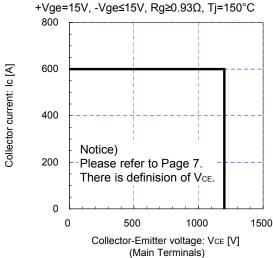
[INVERTER]

Switching loss vs. Collector current (typ.) Vcc=600V Vge= \pm 15V, Rg=0.93 Ω , Tj=125°C, 150°C

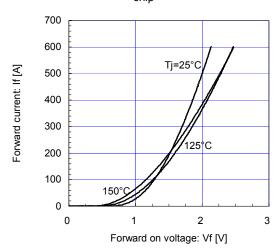


[INVERTER]

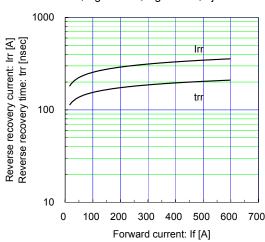
Reverse bias safe operating area (max.)



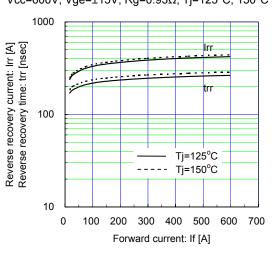
[INVERTER]
Forward Current vs. Forward Voltage (typ.)
chip



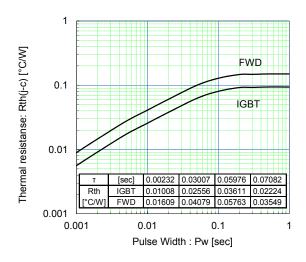
[INVERTER]
Reverse Recovery Characteristics (typ.)
Vcc=600V, Vge=±15V, Rg=0.93Ω, Tj=25°C



[INVERTER]
Reverse Recovery Characteristics (typ.)
Vcc=600V, Vge=±15V, Rg=0.93Ω, Tj=125°C, 150°C

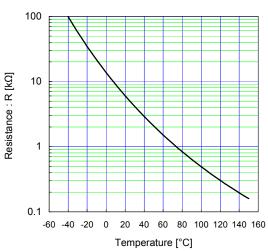


Transient Thermal Resistance (max.)

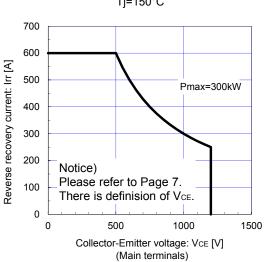


[THERMISTOR]

Temperature characteristic (typ.)



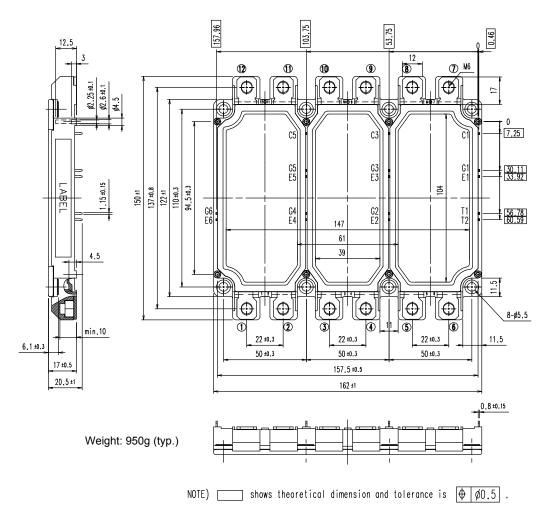
FWD safe operating area (max.) Tj=150°C



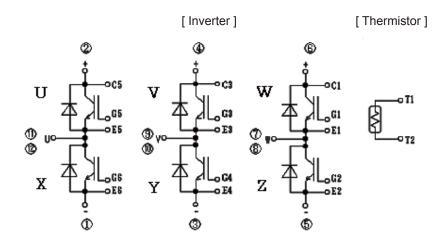
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■ Outline Drawings(Unit:mm)

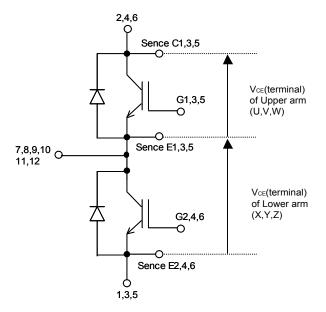


■ Equivalent Circuit



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■ Definition of switching characteristics



Switching characteristics of V_{CE} is defined between Sense C1,3,5 and Sense E1,3,5 for Upper arm(U,V,W) and Sense E1,3,5 and Sense E2,4,6 for Lower arm(X,Y,Z) .

Please use these terminals whenever measure spike voltage.

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 Machine tools
- OA equipmen
- Communications equipment (terminal devices)
- Measurement equipment

- Machine tools
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- Electrical home appliances
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IGBT Modules

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